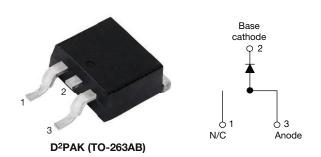


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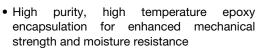
High Performance Schottky Rectifier, 7.5 A



PRIMARY CHARACTERISTICS							
I _{F(AV)}	7.5 A						
V _R	35 V, 45 V						
V _F at I _F	0.57 V						
I _{RM}	15 mA at 125 °C						
T _J max.	150 °C						
E _{AS}	7 mJ						
Package	D ² PAK (TO-263AB)						
Circuit configuration	Single						

FEATURES

- 150 °C T_{.I} operation
- High frequency operation
- · Low forward voltage drop





- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-MBRB7... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL CHARACTERISTICS VALUES									
I _{F(AV)}	Rectangular waveform	7.5	Α						
V _{RRM}		35, 45	V						
I _{FSM}	$t_p = 5 \mu s sine$	690	Α						
V _F	7.5 A _{pk} , T _J = 125 °C	0.57	V						
T _J	Range	-65 to +150	°C						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-MBRB735-M3	VS-MBRB745-M3	UNITS					
Maximum DC reverse voltage	V_R	35	45	V					
Maximum working peak reverse voltage	V_{RWM}	33	45	V					

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST (VALUES	UNITS					
Maximum average forward current	I _{F(AV)}	T_C = 131 °C, rated V_R	7.5						
Non-repetitive peak surge current	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	690	А				
		Surge applied at rated load c	150						
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 2 \text{A}, L = 3.5$	7	mJ					
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero Frequency limited by T_J max	2	А					



VS-MBRB735-M3, VS-MBRB745-M3

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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS				
		15 A	T _J = 25 °C	0.84				
Maximum forward voltage drop	V _{FM} ⁽¹⁾	7.5 A	T 105 °C	0.57	V			
		15 A	T _J = 125 °C	0.72				
Maximum instantaneous reverse current	I _{RM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	0.1	A			
Maximum instantaneous reverse current		T _J = 125 °C	Rated DC voltage	15	mA mA			
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal range	400	pF				
Typical series inductance	L _S	Measured from top of terr	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs				

Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	MBOL TEST CONDITIONS		UNITS			
Maximum junction temperature range		TJ		-65 to 150	°C			
Maximum storage temperat	ure range	T _{Stg}		-65 to 175	- U			
Maximum thermal resistance, junction to case		R_{thJC}	DC operation	3.0	°C/W			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	C/ VV			
Annyayimata waisht				2	g			
Approximate weight				0.07	OZ.			
minimum				6 (5)	kgf · cm			
Mounting torque	maximum				(lbf \cdot in)			
Marking device			Consistual D2DAK (TO 262AB)	MBR	B735			
			Case style D ² PAK (TO-263AB)		B745			

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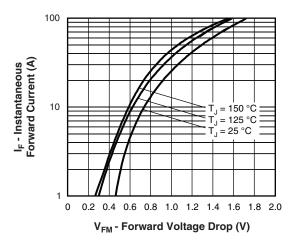


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

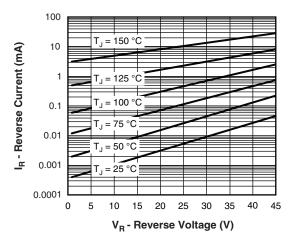


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

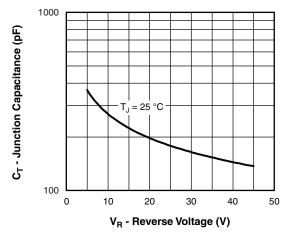


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

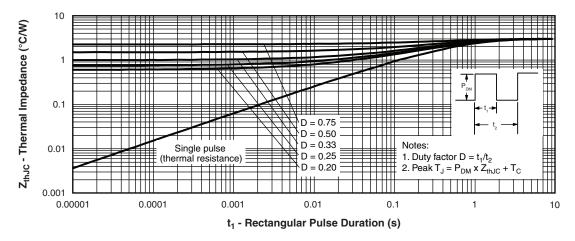


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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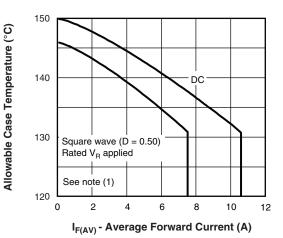


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

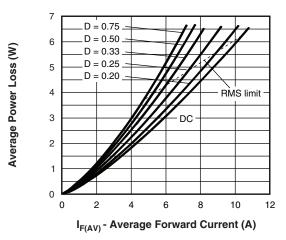


Fig. 6 - Forward Power Loss Characteristics

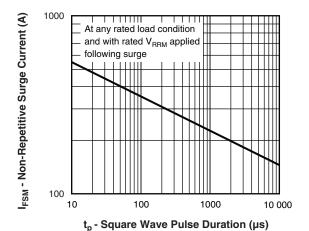


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

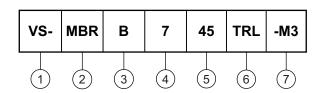
(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}$; $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = rated V_R$

VS-MBRB735-M3, VS-MBRB745-M3

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

- Essential part number

3 - • B = Surface mount

• None = TO-220

Current rating (7 = 7.5 A)

Voltage ratings 35 = 35 V 45 = 45 V

6 - • None = Tube

• TRL = Tape and reel (left oriented - for D²PAK only)

• TRR = Tape and reel (right oriented - for D²PAK only)

7 - -M3 = Halogen-free, RoHS-compliant and termination lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION						
VS-MBRB735-M3	50	Antistatic plastic tubes						
VS-MBRB735TRL-M3	800	13" diameter plastic tape and reel						
VS-MBRB735TRR-M3	800	13" diameter plastic tape and reel						
VS-MBRB745-M3	50	Antistatic plastic tubes						
VS-MBRB745TRL-M3	800	13" diameter plastic tape and reel						
VS-MBRB745TRR-M3	800	13" diameter plastic tape and reel						

LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?96164						
Part marking information	www.vishay.com/doc?95444						
Packaging information	www.vishay.com/doc?96424						
SPICE model	www.vishay.com/doc?95298						



Vishay Semiconductors

D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	ETERS	INC	HES	NOTES	NOTES	<u>.</u> e,	SYMBOL	MILLIMETERS		INCHES		NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES		STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3	
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3	
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3	
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC		
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625		
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110		
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3	
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070		
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC		
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208		

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inches
- (7) Outline conforms to JEDEC® outline TO-263AB

Revision: 13-Jul-17 Document Number: 96164



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